BRIGHT LED ELECTRONICS CORP.

●Device Number: BPD-BQB331

●Absolute Maximum Rating(Ta=25°C) Version:1.0

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Item	Symbol	Rating	Unit
Power Dissipation	Pd	100	mW
Operating Temperature	Topr	-45 ~ +85	$^{\circ}\!\mathbb{C}$
Storage Temperature	Tstg	-45 ~ +100	$^{\circ}\!\mathbb{C}$
Soldering Temperature(*1)	Tsol	250	$^{\circ}\!\mathbb{C}$

(*1), For 5 Sec

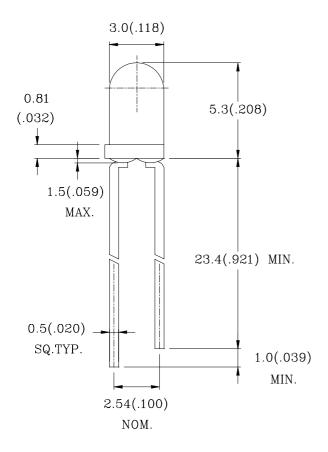
●Electrical And Optical Characteristics(Ta=25°C)

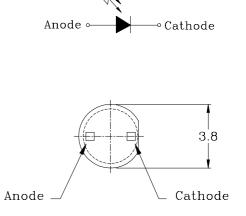
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Reverse Break Down Voltage	$V_{ ext{BR}}$	Ir=100μA, Ee=0mW/cm²	30	_	_	V
Reverse Dark Current	Id	Vr=10V, Ee=OmW/cm ²	_	_	30	nA
Reverse Light Current	IL	Vr=5V, Ee=5mW/cm ²	_	80	_	μ A
Open Circuit Voltage	Voc	Ee=5mW/cm ²	_	420	_	mV
Rise Time	Tr	V 10V D 1VO	_	10	_	ns
Fall Time	Tf	Vr=10V,R∟=1KΩ	_	10	_	ns
Total Capacitance	Ct	Vr=3V,F=1MHz, Ee=OmW/cm ²	_	25	_	pF

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•Dimensions Version: 1.0





Notes:

- 1. All dimensions are in millimeters(inches).
- 2 · Tolerance is ± 0.25 mm(0.01") unless otherwise specified.
- 3 Lead spacing is measured where the leads emerge from the package.
- 4 · Specifications are subject to change without notice.
- 5 Lens appearance: water clear.

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●Device Number:BPD-BQB331

• Electrical And Optical Curves (Ta=25°C)

FIG.1 Relative Spectral Sensitivity Vs. Wavelength

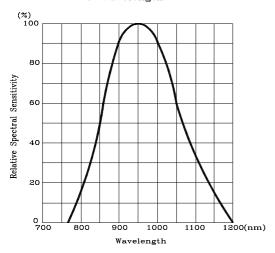


FIG.3 Dark Current Vs. Reverse Voltage $\label{eq:Ta=25°C} Ta=25^{\circ}C; Ee=0mW/cm^2$

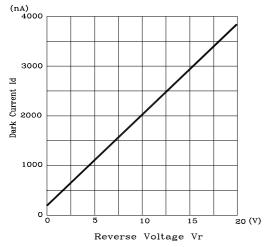


Fig.5 Photocurrent Vs.
Ambient Temperature

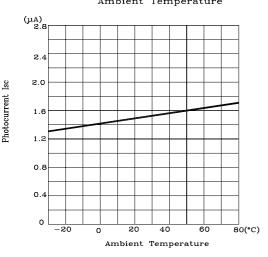


FIG.2 Capacitance Vs. Reverse Voltage $F=1 MHz, Ee=0 mW/cm^2$

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Version:1.0

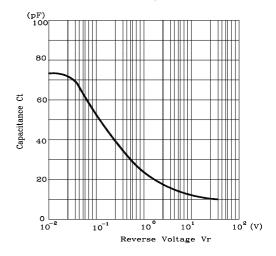


FIG.4 Total Power Dissipation Vs. Ambient Tempertaure

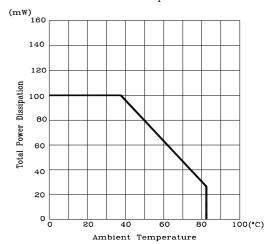


FIG.6 Dark Current Vs.
Ambient Temperature

